

MITSUBISHI Nch POWER MOSFET

# FS7UM-16A

HIGH-SPEED SWITCHING USE

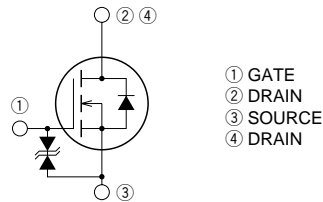
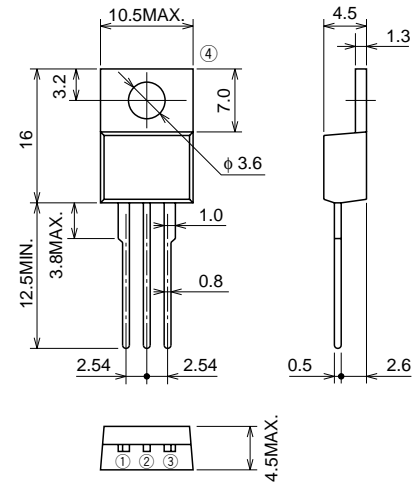
## FS7UM-16A



- V<sub>DSS</sub> ..... 800V
- r<sub>DS (ON)</sub> (MAX) ..... 1.64Ω
- I<sub>D</sub> ..... 7A

## OUTLINE DRAWING

Dimensions in mm



TO-220

## APPLICATION

SMPS, DC-DC Converter, battery charger, power supply of printer, copier, HDD, FDD, TV, VCR, personal computer etc.

## MAXIMUM RATINGS (T<sub>c</sub> = 25°C)

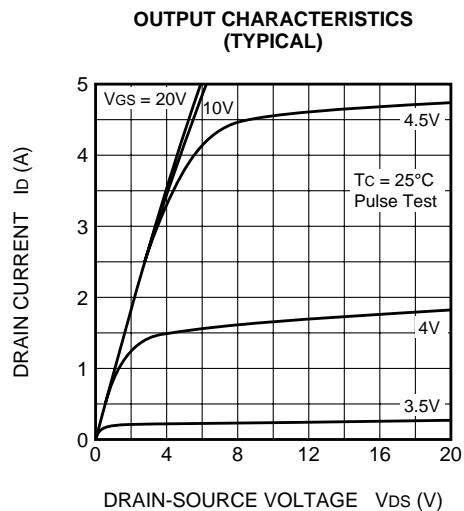
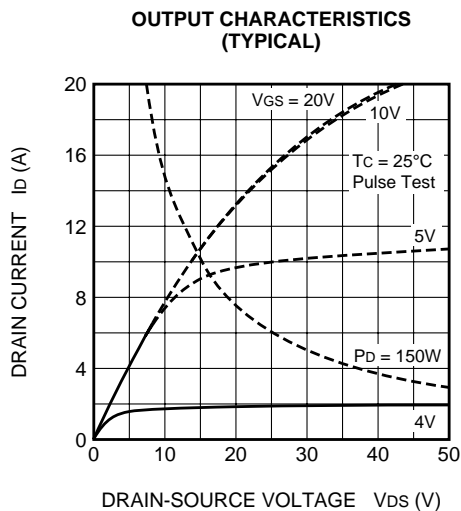
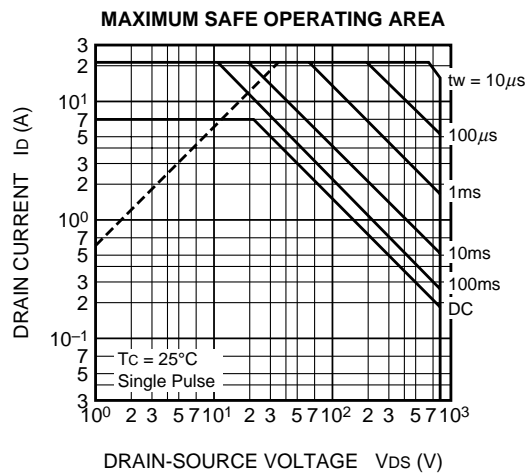
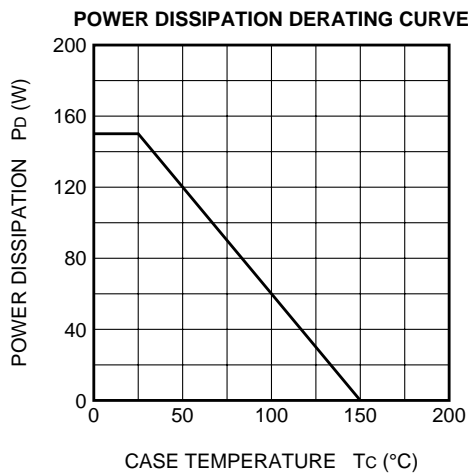
Symbol	Parameter	Conditions	Ratings	Unit
V <sub>DSS</sub>	Drain-source voltage	V <sub>GS</sub> = 0V	800	V
V <sub>GSS</sub>	Gate-source voltage	V <sub>DS</sub> = 0V	±30	V
I <sub>D</sub>	Drain current		7	A
I <sub>DM</sub>	Drain current (Pulsed)		21	A
P <sub>D</sub>	Maximum power dissipation		150	W
T <sub>ch</sub>	Channel temperature		-55 ~ +150	°C
T <sub>stg</sub>	Storage temperature		-55 ~ +150	°C
—	Weight	Typical value	2	g

Feb.1999

**ELECTRICAL CHARACTERISTICS** (Tch = 25°C)

Symbol	Parameter	Test conditions	Limits			Unit
			Min.	Typ.	Max.	
V (BR) DSS	Drain-source breakdown voltage	Id = 1mA, VGS = 0V	800	—	—	V
V (BR) GSS	Gate-source breakdown voltage	IGS = ±100μA, VDS = 0V	±30	—	—	V
IGSS	Gate-source leakage current	VGS = ±25V, VDS = 0V	—	—	±10	μA
IdSS	Drain-source leakage current	VDS = 800V, VGS = 0V	—	—	1	mA
VGS (th)	Gate-source threshold voltage	Id = 1mA, VDS = 10V	2	3	4	V
rDS (ON)	Drain-source on-state resistance	Id = 3A, VGS = 10V	—	1.26	1.64	Ω
VDS (ON)	Drain-source on-state voltage	Id = 3A, VGS = 10V	—	3.78	4.92	V
yfs	Forward transfer admittance	Id = 3A, VDS = 10V	4.2	7.0	—	S
Ciss	Input capacitance	VDS = 25V, VGS = 0V, f = 1MHz	—	1380	—	pF
Coss	Output capacitance		—	140	—	pF
Crss	Reverse transfer capacitance		—	28	—	pF
td (on)	Turn-on delay time		—	25	—	ns
tr	Rise time	VDD = 200V, Id = 3A, VGS = 10V, RGEN = RGS = 50Ω	—	28	—	ns
td (off)	Turn-off delay time		—	185	—	ns
tf	Fall time		—	46	—	ns
VSD	Source-drain voltage	IS = 3A, VGS = 0V	—	1.0	1.5	V
Rth (ch-c)	Thermal resistance	Channel to case	—	—	0.83	°C/W

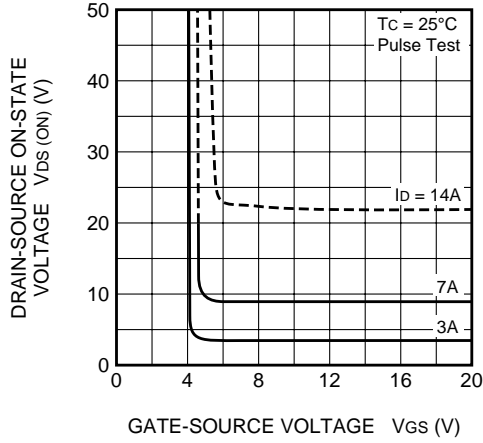
**PERFORMANCE CURVES**



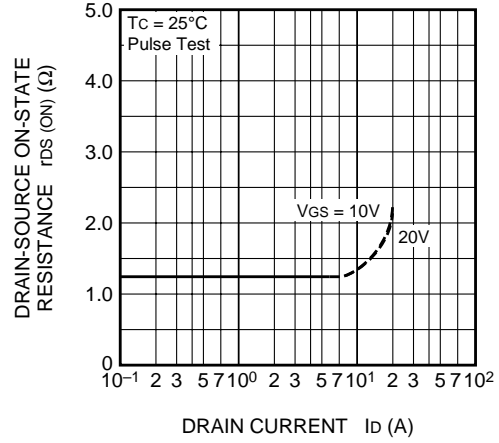
# FS7UM-16A

## HIGH-SPEED SWITCHING USE

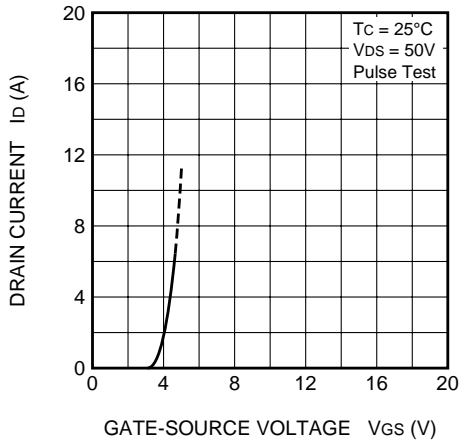
**ON-STATE VOLTAGE VS. GATE-SOURCE VOLTAGE (TYPICAL)**



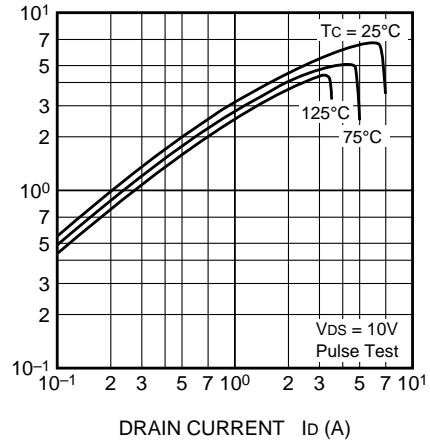
**ON-STATE RESISTANCE VS. DRAIN CURRENT (TYPICAL)**



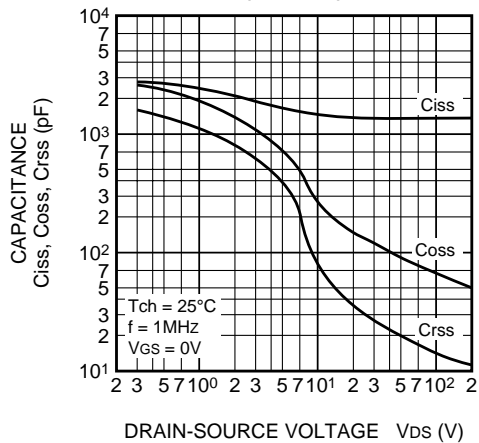
**TRANSFER CHARACTERISTICS (TYPICAL)**



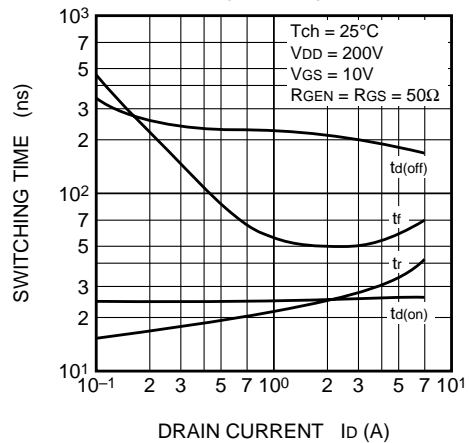
**FORWARD TRANSFER ADMITTANCE VS. DRAIN CURRENT (TYPICAL)**



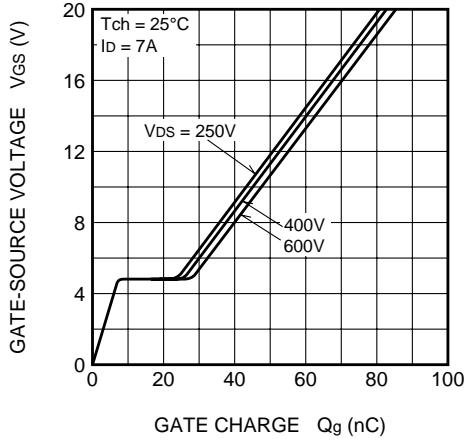
**CAPACITANCE VS. DRAIN-SOURCE VOLTAGE (TYPICAL)**



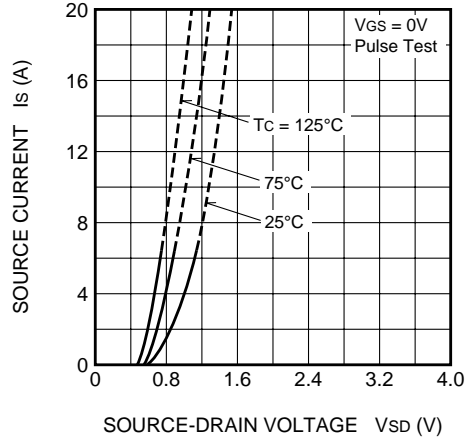
**SWITCHING CHARACTERISTICS (TYPICAL)**



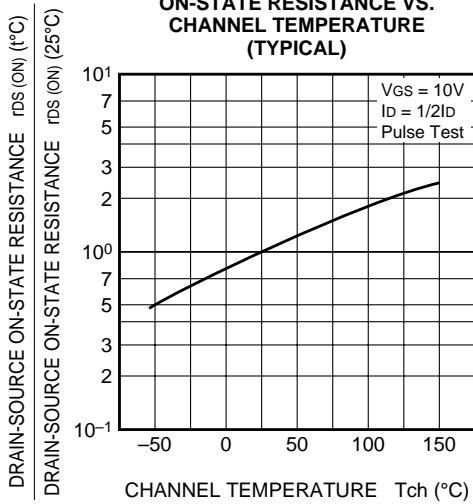
**GATE-SOURCE VOLTAGE VS. GATE CHARGE (TYPICAL)**



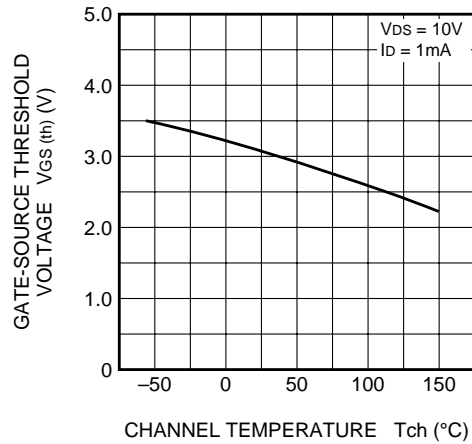
**SOURCE-DRAIN DIODE FORWARD CHARACTERISTICS (TYPICAL)**



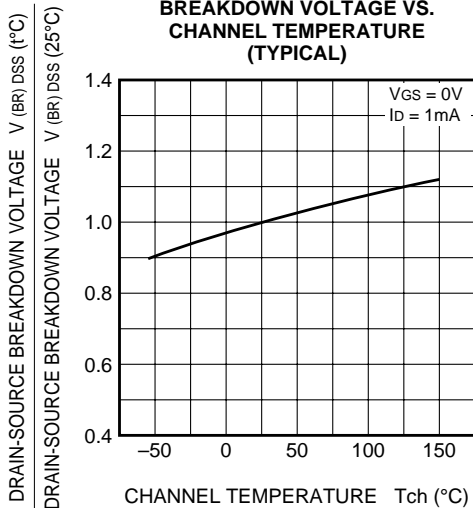
**ON-STATE RESISTANCE VS. CHANNEL TEMPERATURE (TYPICAL)**



**THRESHOLD VOLTAGE VS. CHANNEL TEMPERATURE (TYPICAL)**



**BREAKDOWN VOLTAGE VS. CHANNEL TEMPERATURE (TYPICAL)**



**TRANSIENT THERMAL IMPEDANCE CHARACTERISTICS**

